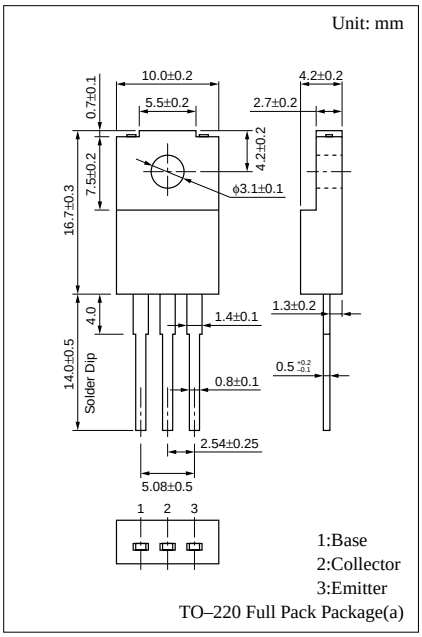
2SA1614

Silicon PNP triple diffusion planar type

For high-speed switching



Features

- High-speed switching
- High collector to base voltage V_{CBO}
- Wide area of safe operation (ASO)
- Satisfactory linearity of foward current transfer ratio h_{FE}
- Full-pack package which can be installed to the heat sink with one screw

Absolute Maximum Ratings (T_C=25˚C)

Parameter		Symbol	Ratings	Unit
Collector to base voltage		V_{CBO}	–400	V
Collector to emitter voltage		V_{CEO}	–400	V
Emitter to base voltage		V_{EBO}	–7	V
Peak collector current		I_{CP}	–1	A
Collector current		I_C	– 0.5	A
Collector power dissipation	T_C=25°C	P_C	25	W
	Ta=25°C		2	
Junction temperature		T_j	150	˚C
Storage temperature		T_{stg}	–55 to +150	˚C

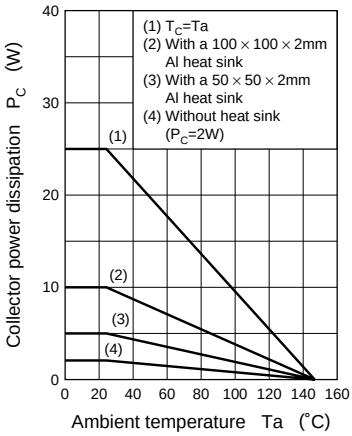
Electrical Characteristics (T_C=25˚C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I_{CBO}	V_{CB} = –400V, I_E = 0			–100	μA
Emitter cutoff current	I_{EBO}	V_{EB} = –7V, I_C = 0			–100	μA
Collector to emitter voltage	V_{CEO}	I_C = –10mA, I_B = 0	–400			V
Forward current transfer ratio	h_{FE1}*	V_{CE} = –5V, I_C = –50mA	80		280	
	h_{FE2}	V_{CE} = –5V, I_C = – 0.3A	10			
Collector to emitter saturation voltage	$V_{CE(sat)}$	I_C = – 0.2A, I_B = –40mA			–1.5	V
Base to emitter saturation voltage	$V_{BE(sat)}$	I_C = – 0.2A, I_B = –40mA			–1.5	V
Transition frequency	f_T	V_{CE} = –10V, I_C = – 0.1A, f = 1MHz		20		MHz
Turn-on time	t_{on}	I_C = – 0.3A,		0.25		μs
Storage time	t_{stg}	I_{B1} = –60mA, I_{B2} = 60mA,		2.0		μs
Fall time	t_f	V_{CC} = –200V		0.5		μs

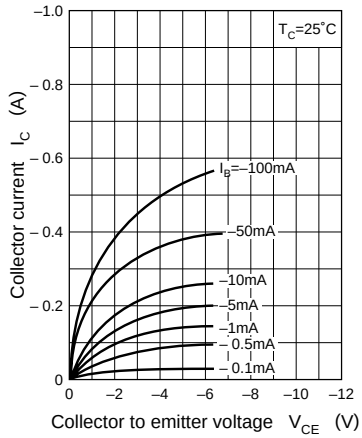
*h_{FE1} Rank classification

Rank	Q	P
h_{FE1}	80 to 160	130 to 280

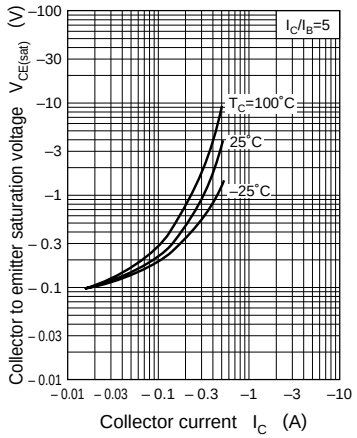
P_C — Ta



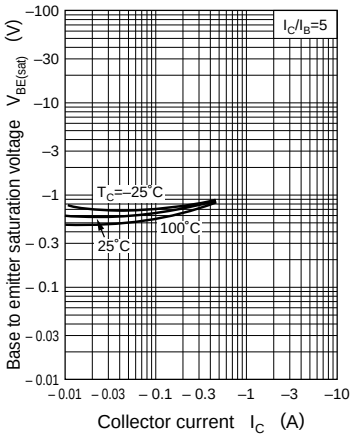
I_C — V_{CE}



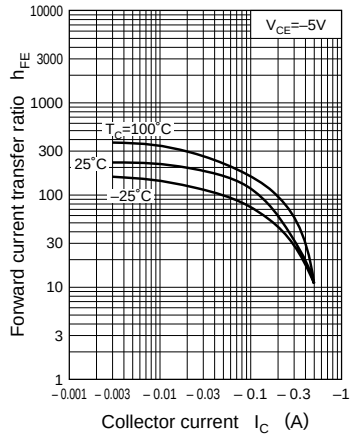
$V_{CE(sat)}$ — I_C



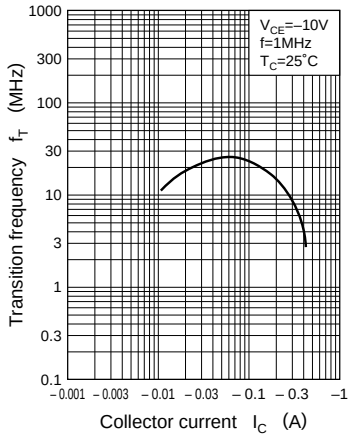
$V_{BE(sat)}$ — I_C



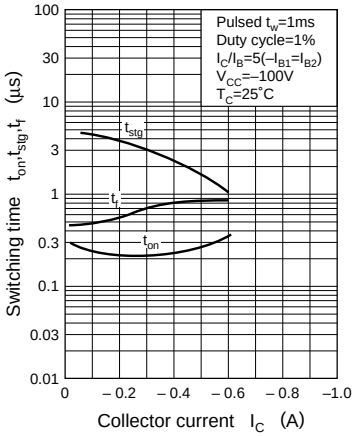
h_{FE} — I_C



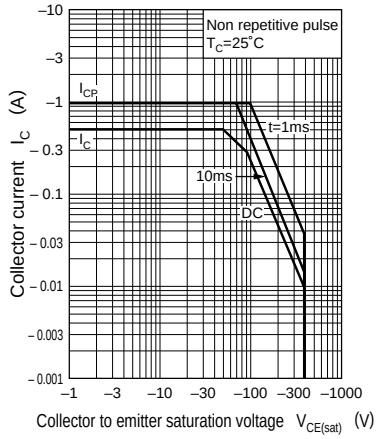
f_T — I_C



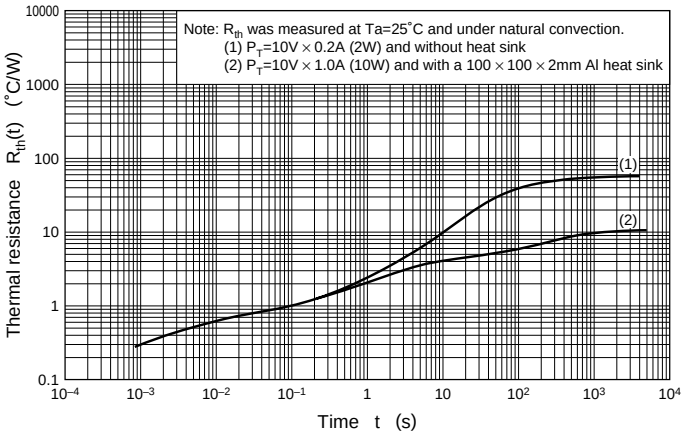
t_{on}, t_{stg}, t_f — I_C



Area of safe operation (ASO)



$R_{th(t)}$ — t


Note: R_{th} was measured at Ta=25°C and under natural convection.
(1) P_T=10V × 0.2A (2W) and without heat sink
(2) P_T=10V × 1.0A (10W) and with a 100 × 100 × 2mm Al heat sink
Thermal resistance R_{th}(t) (°C/W)
10000
1000
100
10
1
0.1
(1)
(2)
10^{-4}
10^{-3}
10^{-2}
10^{-1}
1
10
10^{2}
10^{3}
10^{4}
Time t (s)